NSN 5961-01-075-6826

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Inclosure Material:

Metal

Overall Length:

Between 0.240 inches and 0.260 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.350 inches and 0.370 inches

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

T0-39

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-100.0 collector to base voltage/static/emitter open and -80.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between -2.50 amperes source cutoff current and -5.00 amperes source cutoff current

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Test Data Document:

96214-802745 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0